

**In the Specification**

Please amend the title as follows:

~~Transistor Devices, CMOS Constructions, and Capacitor~~  
~~Constructions, and Methods of Forming Transistor Devices and Capacitor Constructions~~

At page 1, before the "Technical Field" section, please insert,

**RELATED PATENT DATA**

This patent resulted from a divisional application of U.S. Patent Application Serial  
No. 10/388,103, which was filed March 12, 2003.